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OX-205 at 100 MHz

Ultra Low Phase Noise Oven Controlled Crystal Oscillator



The OX-205 is an Ultra Low Phase Noise Ovenized Crystal Oscillator with a noise floor as low as -176 dBc/Hz in a compact 1" x 1" enclosure. Designed for applications that demand extremely low noise sources, including the reference oscillator for a phase-locked loop in the microwave spectrum. Custom frequencies available upon request.

Features

- -135 dBc/ Hz at 100 Hz offset
- · -176 dBc/Hz at 100 kHz offset

Warm up time

- 100 MHZ standard, other frequencies available
- Compact 1" x 1" hermetic enclosure

Applications

@+25°C

- Military Radar
- Instrumentation and Test Equipment
- Synthesizers
- Military Communication Equipment
- DRO reference
- Satellite Communications

Performance Specifications

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Phase Noise Ordering Codes at 100 MHz							
Frequency Offset (Hz)	А	В	С	Unit	Condition		
10	-100	-102	-105	dBc/Hz			
100	-130	-132	-135	dBc/Hz	Maximum values		
1000	-150	-156	-159	dBc/Hz	All EFC settings		
10,000	-165	-168	-170	dBc/Hz	Static Environment		
100,000	-175	-175	-176	dBc/Hz			
Frequency Stabilities at 100 MHz							
Parameter	Min	Typical	Max	Unit	Condition		
	-100		+100	ppb	-20 to +70°C (referenced to +25°C)		
vs. operating temperature range	-200		+200	ppb	-40 to +85°C (referenced to +25°C)		
vs. Initial Tolerance	-500		+500	ppb	at time of shipment and only applies to ordering codes with no EFC tuning		
Allan Deviation			1	E-11	0.1 to 1 second tau		
vs. supply voltage change	-10		+10	ppb	±5% change		
vs. load change	-10		+10	ppb	5% change in load		
vs. aging / 1 day	-5		+5	ppb	after 30 days of operation		
vs. aging / 1 st year	-200		+200	ppb	after 30 days of operation		
vs. aging / 10 year	-1.5		+1.5	ppm	after 30 days of operation		
Warm un time			5	minutes	to ± 100 ppb of 2-hour frequency		

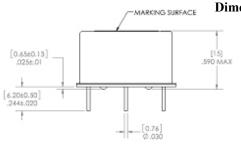
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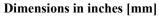
minutes

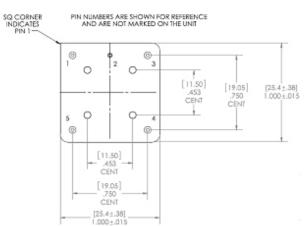
Performance Specifications

		Supp	ly Voltage	(Vs)	
Parameter	Min	Typical	Max	Unit	Condition
Supply Voltage	11.4	12.0	12.6	VDC	
Power Consumption			4.5 1.8	Watts Watts	during warm-up steady state @ +25°C
Reference Voltage	9.8	10	1.3	VDC	
Nelefence voltage	9.0		RF Output	VDC	
Signal	Ì		wave		
Load		50		Ohms	
Output Power	+9.0	50	+13.0	dBm	50 Ohm load
Harmonics	1 9.0		-30	dBc	50 Ohm load
Spurious			-80	dBc	50 Ohm load
Spunous		Ereque	ncy Tuning		50 chimidad
Tuning Dange	115	Fleque			1
Tuning Range	±1.5		±3.0	ppm	
Linearity		_	20	%	
Tuning Slope		Pos	sitive I		
Control Voltage Range	0		10	VDC	
Input Impedance		20		kOhm	
Modulation Bandwidth	150			Hz	
		Additi	onal Param	eters	
g- Sensitivity			1	ppb/g	worst axis
Weight			20	grams	
		Absolute	Maximum	Ratings	
Parameter	Min	Typical	Max	Unit	Condition
Supply Voltage (Vs)			15	V	
Output Load			25	Ohms	
Operable Temperature Range	-55		+95	°C	Device will not sustain damage when operated at temperatures between the operating range and the operable range, but will not be specification compliant.
	Envi	ronmental	and Produc	t Classificatio	n
Shock (Endurance) MIL-STD-202, Method 213, Condition J, 30 g 11 ms					
Sine Vibration (Endurance)	MIL-STD-202, Method 201 and 204, Condition A, except 5 g to 500 Hz, 1 sweep each axis				
Random Vibration (Endurance)	MIL-STD-202, Method 214, Condition I-D				
Humidity	MIL-STD-202, Method 103, Condition B, 100% rh				
Seal	MIL-STD-202, Method 112, Condition D				
Altitude	MIL-STD-202, Method 105, sea level to30,000 ft				
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition A,B,C				
Terminal Strength	MIL-STD-202, Method 11, Condition C (5 bends at 45°, 2 lbs)				
Moisture Sensitive Level	1				
RoHS	6 (fully compliant) - no pure tin options available upon request, the device will be assigned a customer part number , not orderable through ordering codes				
Storage Temperature Range	-55		+125	°C	

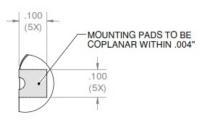
Outline Drawing



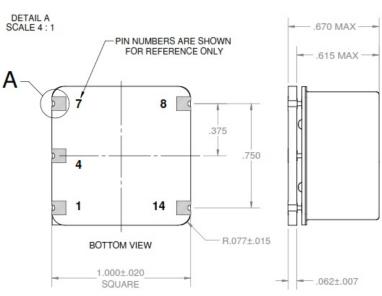




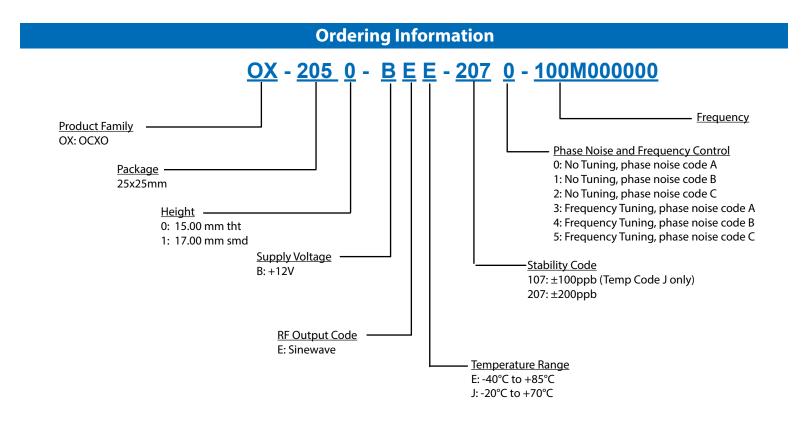
Code	Height "H"	Pin Length "L" Min					
0	15.0	6.2					
	Pin Connections						
1	RF Output						
2	Ground (Case)						
3	Electronic Frequency Control Input (EFC)						
4	Reference Voltage						
5	Supply Voltage Input (VS)						



Dimensions in inches



Code	Height "H"	Pin Length "L" Min				
1	17.0 mm	na				
Pin Connections						
1	RF Output					
4	Ground (Case)					
7	Electronic Frequency Control Input (EFC) No Connect for Fixed frequency Oscillators					
8	Reference Voltage					
14	Supply Voltage Input (VS)					



Notes:

- 1. Unless otherwise stated, all values are valid after warm-up time and refer to typical conditions for supply voltage, frequency control voltage, load, and temperature (25°C).
- 2. Contact factory for other frequencies. Phase noise degrades for frequencies greater than 100 MHz.
- 3. Subject to technical modification.
- 4. Contact factory for availability.



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